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Team Nexperia

74CBTLV3125

4-bit bus switch
Rev. 4 — 9 November 2016

Product data sheet

General description 1.

The 74CBTLV3125 provides a 4-bit high-speed bus switch with separate output enable inputs (10E to 40E). The low on-state resistance of the switch allows connections to be made with minimal propagation delay. The switch is disabled (high-impedance OFF-state) when the output enable (nOE) input is HIGH.

To ensure the high-impedance OFF-state during power-up or power-down, nOE should be tied to the V_{CC} through a pull-up resistor. The minimum value of the resistor is determined by the current-sinking capability of the driver.

Schmitt trigger action at control input makes the circuit tolerant to slower input rise and fall times across the entire V_{CC} range from 2.3 V to 3.6 V.

This device is fully specified for partial power-down applications using I_{OFF}. The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

Features and benefits 2.

- Supply voltage range from 2.3 V to 3.6 V
- Standard '125'-type pinout
- High noise immunity
- Complies with JEDEC standard:
 - ◆ JESD8-5 (2.3 V to 2.7 V)
 - ◆ JESD8-B/JESD36 (2.7 V to 3.6 V)
- ESD protection:
 - ◆ HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM AEC-Q100-011 revision B exceeds 1000 V
- \blacksquare 5 Ω switch connection between two ports
- Rail to rail switching on data I/O ports
- CMOS low power consumption
- Latch-up performance exceeds 250 mA per JESD78B Class I level A
- I_{OFF} circuitry provides partial Power-down mode operation
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C



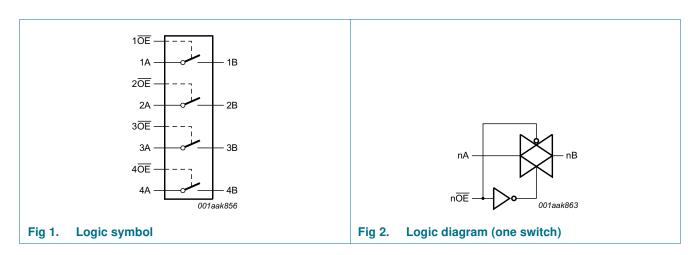
3. Ordering information

Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74CBTLV3125DS	–40 °C to +125 °C	SSOP16[1]	plastic shrink small outline package; 16 leads; body width 3.9 mm; lead pitch 0.635 mm	SOT519-1
74CBTLV3125PW	–40 °C to +125 °C	TSSOP14	plastic thin shrink small outline package; 14 leads; body width 4.4 mm	SOT402-1
74CBTLV3125BQ	–40 °C to +125 °C	DHVQFN14	plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 14 terminals; body $2.5 \times 3 \times 0.85$ mm	SOT762-1

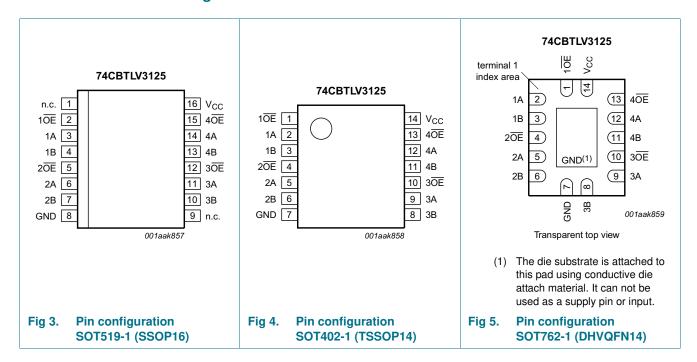
^[1] Also known as QSOP16.

4. Functional diagram



5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

Table 2. Thi descrip			
Symbol	Pin		Description
	SOT519-1	SOT402-1 and SOT762-1	
1 OE , 2 OE , 3 OE , 4 OE	2, 5, 12, 15	1, 4, 10, 13	output enable input
1A, 2A, 3A, 4A,	3, 6, 11, 14	2, 5, 9, 12	A input/output
1B, 2B, 3B, 4B	4, 7, 10, 13	3, 6, 8, 11	B output/input
GND	8	7	ground (0 V)
V _{CC}	16	14	positive supply voltage
n.c.	1, 9	-	not connected

6. Functional description

Table 3. Function table[1]

Output enable input OE	Function switch
L	ON-state
Н	OFF-state

[1] H = HIGH voltage level; L = LOW voltage level.

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+4.6	V
VI	input voltage	control inputs [1]	-0.5	+4.6	V
V_{SW}	switch voltage	enable and disable mode [2]	-0.5	V _{CC} + 0.5	V
I _{IK}	input clamping current	V _I < -0.5 V	-50	-	mA
I _{SK}	switch clamping current	V _I < -0.5 V	-50	-	mA
I _{SW}	switch current	$V_{SW} = 0 V \text{ to } V_{CC}$	-	±128	mA
I _{CC}	supply current		-	+100	mA
I _{GND}	ground current		-100	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$	-	500	mW

^[1] The minimum input voltage rating may be exceeded if the input clamping current ratings are observed.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		2.3	3.6	V
VI	input voltage	control inputs	0	3.6	V
V_{SW}	switch voltage	enable and disable mode	0	V _{CC}	V
T _{amb}	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	pin n \overline{OE} ; V _{CC} = 2.3 V to 3.6 V	0	200	ns/V

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions voltages are referenced to GND (ground = 0 V).

Symbol Parameter		Conditions	T _{amb} =	–40 °C to +	-85 °C	T _{amb} = -40 °	C to +125 °C	Unit
			Min	Typ[1]	Max	Min	Max	
V _{IH} HIGH-level input voltage	V _{CC} = 2.3 V to 2.7 V	1.7	-	-	1.7	-	V	
	input voltage	V _{CC} = 3.0 V to 3.6 V	2.0	-	-	2.0	-	
V _{IL} LOW-level in	LOW-level input	V _{CC} = 2.3 V to 2.7 V	-	-	0.7	-	0.7	V
	voltage	V _{CC} = 3.0 V to 3.6 V	-	-	0.9	-	0.9	V
lı	input leakage current	pin \overline{OE} ; $V_I = GND$ to V_{CC} ; $V_{CC} = 3.6 \text{ V}$	-	-	±1.0	-	±20	μА
I _{S(OFF)}	OFF-state leakage current	V _{CC} = 3.6 V; see <u>Figure 6</u>	-	-	±1	-	±20	μА

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^[2] The switch voltage ratings may be exceeded if switch clamping current ratings are observed

^[3] For SSOP16 and TSSOP14 packages: P_{tot} derates linearly with 5.5 mW/K above 60 °C. For DHVQFN14 packages: P_{tot} derates linearly with 4.5 mW/K above 60 °C.

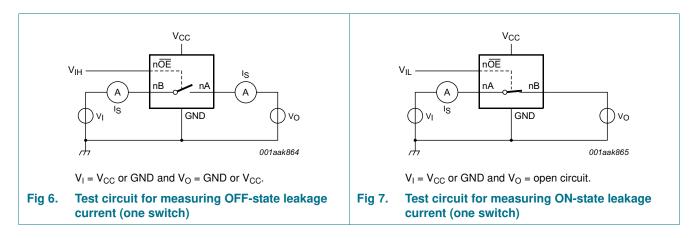
Table 6. Static characteristics ...continued

At recommended operating conditions voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	T _{amb} =	–40 °C to ⋅	⊦85 °C	T _{amb} = -40 °	C to +125 °C	Unit
			Min	Typ[1]	Max	Min	Max	
I _{S(ON)}	ON-state leakage current	V _{CC} = 3.6 V; see <u>Figure 7</u>	-	-	±1	-	±20	μΑ
l _{OFF}	power-off leakage current	$V_1 \text{ or } V_O = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V}$	-	-	±10	-	±50	μΑ
I _{CC}	supply current	$\begin{split} &V_{I} = \text{GND or } V_{CC}; \ I_{O} = 0 \ \text{A}; \\ &V_{SW} = \text{GND or } V_{CC}; \\ &V_{CC} = 3.6 \ \text{V} \end{split}$	-	-	10	-	50	μΑ
Δl _{CC}	additional supply current	$\begin{aligned} &\text{pin } n\overline{\text{OE}}; V_{I} = V_{CC} - 0.6 \text{V}; \\ &V_{SW} = \text{GND or } V_{CC}; \\ &V_{CC} = 3.6 \text{V} \end{aligned}$	-	-	300	-	2000	μΑ
Cı	input capacitance	pin n \overline{OE} ; V _{CC} = 3.3 V; V _I = 0 V to 3.3 V	-	0.9	-	-	-	pF
C _{S(OFF)}	OFF-state capacitance	$V_{CC} = 3.3 \text{ V}; V_I = 0 \text{ V to } 3.3 \text{ V}$	-	5.2	-	-	-	pF
C _{S(ON)}	ON-state capacitance	$V_{CC} = 3.3 \text{ V}; V_{I} = 0 \text{ V to } 3.3 \text{ V}$	-	14.3	-	-	-	pF

- [1] All typical values are measured at T_{amb} = 25 °C.
- [2] One input at 3 V, other inputs at V_{CC} or GND.

9.1 Test circuits



9.2 ON resistance

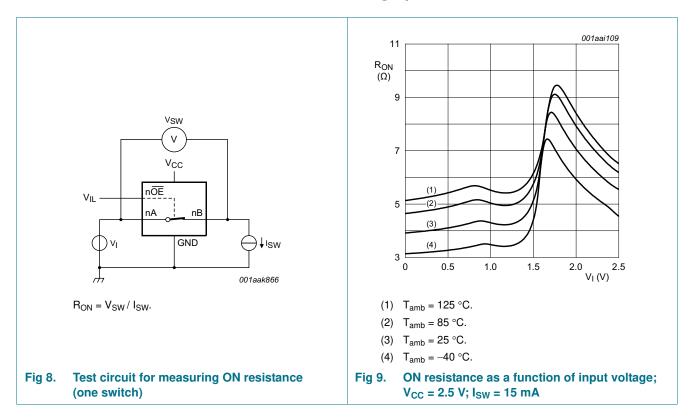
Table 7. Resistance R_{ON}

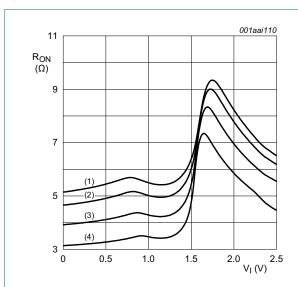
At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for test circuit see Figure 8.

Symbol	Parameter	Conditions			T _{amb} = -40 °	C to +125 °C	Unit	
			Min	Typ[1]	Max	Min	Max	
R _{ON}	ON resistance	V _{CC} = 2.3 V to 2.7 V; see <u>Figure 9</u> to <u>Figure 11</u>						
		$I_{SW} = 64 \text{ mA}; V_I = 0 \text{ V}$	-	4.2	8.0	-	15.0	Ω
		$I_{SW} = 24 \text{ mA}; V_I = 0 \text{ V}$	-	4.2	8.0	-	15.0	Ω
		$I_{SW} = 15 \text{ mA}; V_I = 1.7 \text{ V}$	-	8.4	40.0	-	60.0	Ω
		V _{CC} = 3.0 V to 3.6 V; see <u>Figure 12</u> to <u>Figure 14</u>						
		$I_{SW} = 64 \text{ mA}; V_I = 0 \text{ V}$	-	4.0	7.0	-	11.0	Ω
		$I_{SW} = 24 \text{ mA}; V_I = 0 \text{ V}$	-	4.0	7.0	-	11.0	Ω
		$I_{SW} = 15 \text{ mA}; V_I = 2.4 \text{ V}$	-	6.2	15.0	-	25.5	Ω

- [1] Typical values are measured at T_{amb} = 25 °C and nominal V_{CC} .
- [2] Measured by the voltage drop between the A and B terminals at the indicated current through the switch. ON-state resistance is determined by the lower of the voltages of the two (A or B) terminals.

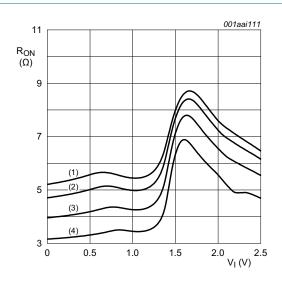
9.3 ON resistance test circuit and graphs





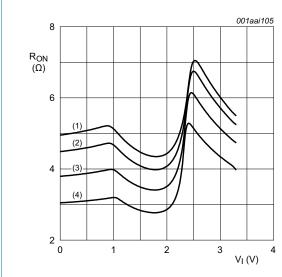
- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.
- (4) $T_{amb} = -40 \, ^{\circ}C$.

Fig 10. ON resistance as a function of input voltage; $V_{CC} = 2.5 \text{ V}; I_{SW} = 24 \text{ mA}$



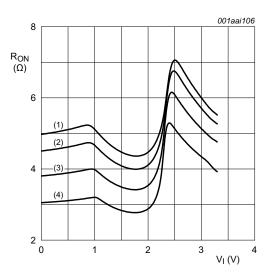
- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.
- (4) $T_{amb} = -40 \, ^{\circ}C$.

Fig 11. ON resistance as a function of input voltage; $V_{CC} = 2.5 \text{ V}; I_{SW} = 64 \text{ mA}$



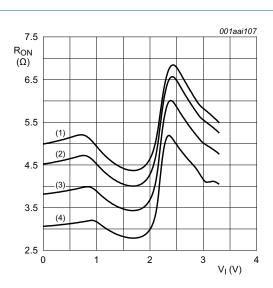
- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.
- (4) $T_{amb} = -40 \, ^{\circ}C$.

Fig 12. ON resistance as a function of input voltage; $V_{CC} = 3.3 \text{ V}; I_{SW} = 15 \text{ mA}$



- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.
- (4) $T_{amb} = -40 \, ^{\circ}C$.

Fig 13. ON resistance as a function of input voltage; $V_{CC} = 3.3 \text{ V}; I_{SW} = 24 \text{ mA}$



- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.
- (4) $T_{amb} = -40 \, ^{\circ}C$.

Fig 14. ON resistance as a function of input voltage; $V_{CC} = 3.3 \text{ V}$; $I_{SW} = 64 \text{ mA}$

10. Dynamic characteristics

Table 8. Dynamic characteristics GND = 0 V; for test circuit see Figure 17

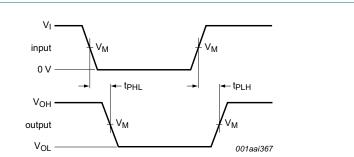
Symbol	Parameter	Conditions	T _{amb} =	–40 °C to	+85 °C	T _{amb} = -40 °	C to +125 °C	Unit
			Min	Typ[1]	Max	Min	Max	
t _{pd}	propagation delay	nA to nB or nB to nA; [2][3] see Figure 15						
		V _{CC} = 2.3 V to 2.7 V	-	-	0.13	-	0.20	ns
		V _{CC} = 3.0 V to 3.6 V	-	-	0.20	-	0.31	ns
t _{en}	enable time	nOE to nA or nB; [4] see Figure 16						
		V _{CC} = 2.3 V to 2.7 V	1.0	2.7	4.6	1.0	6.0	ns
		V _{CC} = 3.0 V to 3.6 V	1.0	2.4	4.4	1.0	6.0	ns
t _{dis}	disable time	nOE to nA or nB; [5] see Figure 16						
		V _{CC} = 2.3 V to 2.7 V	1.0	2.2	3.9	1.0	5.5	ns
		V _{CC} = 3.0 V to 3.6 V	1.0	2.9	4.2	1.0	5.5	ns

- [1] All typical values are measured at T_{amb} = 25 °C and at nominal V_{CC} .
- [2] The propagation delay is the calculated RC time constant of the typical on-state resistance of the switch and the load capacitance, when driven by an ideal voltage source (zero output impedance).
- [3] t_{pd} is the same as t_{PLH} and t_{PHL} .
- [4] t_{en} is the same as t_{PZH} and t_{PZL} .
- [5] t_{dis} is the same as t_{PHZ} and t_{PLZ} .

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11. Waveforms



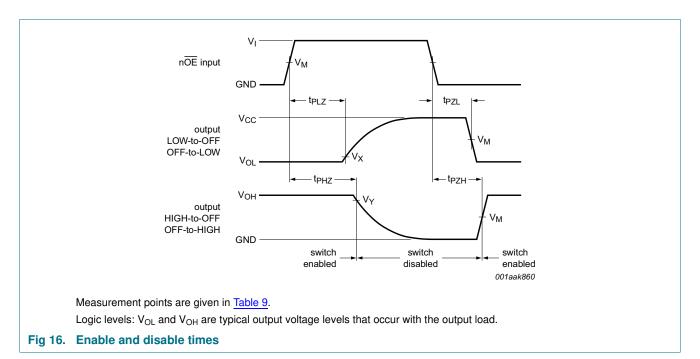
Measurement points are given in Table 9.

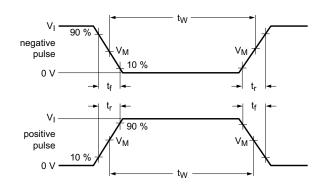
Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

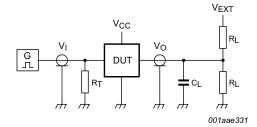
Fig 15. The data input (nA or nB) to output (nB or nA) propagation delays

Table 9. Measurement points

Supply voltage	Input			Output		
V _{CC}	V _M	VI	$t_r = t_f$	V _M	V _X	V _Y
2.3 V to 2.7 V	0.5V _{CC}	V _{CC}	≤ 2.0 ns	0.5V _{CC}	V _{OL} + 0.15 V	V _{OH} – 0.15 V
3.0 V to 3.6 V	0.5V _{CC}	V _{CC}	≤ 2.0 ns	0.5V _{CC}	V _{OL} + 0.3 V	V _{OH} – 0.3 V







Test data is given in Table 10.

Definitions for test circuit:

R_L = Load resistance.

 C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to the output impedance Z_0 of the pulse generator.

 V_{EXT} = External voltage for measuring switching times.

Fig 17. Test circuit for measuring switching times

Table 10. Test data

Supply voltage	Load		V _{EXT}			
V _{CC}	CL	R _L	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t_{PZL} , t_{PLZ}	
2.3 V to 2.7 V	30 pF	500 Ω	open	GND	2V _{CC}	
3.0 V to 3.6 V	50 pF	500 Ω	open	GND	2V _{CC}	

11.1 Additional dynamic characteristics

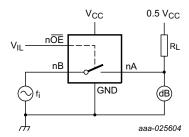
Table 11. Additional dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); $V_I = GND$ or V_{CC} (unless otherwise specified); $t_r = t_f \le 2.5$ ns.

Symbol	Parameter	Conditions	T _{amb} = 25 °C			Unit
			Min	Тур	Max	
f _(-3dB)	-3 dB frequency response	$V_{CC} = 3.3 \text{ V}; R_L = 50 \Omega; \text{ see } \frac{\text{Figure 18}}{}$	-	406	-	MHz

[1] f_i is biased at $0.5V_{CC}$.

11.2 Test circuit



 $n\overline{OE}$ connected to GND; Adjust f_i voltage to obtain 0 dBm level at output. Increase f_i frequency until dB meter reads -3 dB.

Fig 18. Test circuit for measuring the frequency response when channel is in ON-state

12. Package outline

SSOP16: plastic shrink small outline package; 16 leads; body width 3.9 mm; lead pitch 0.635 mm SOT519-1

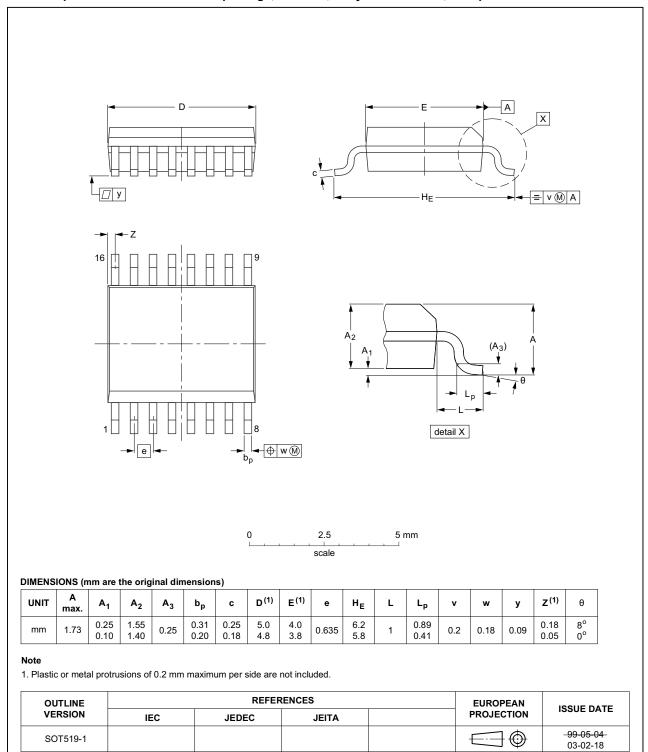


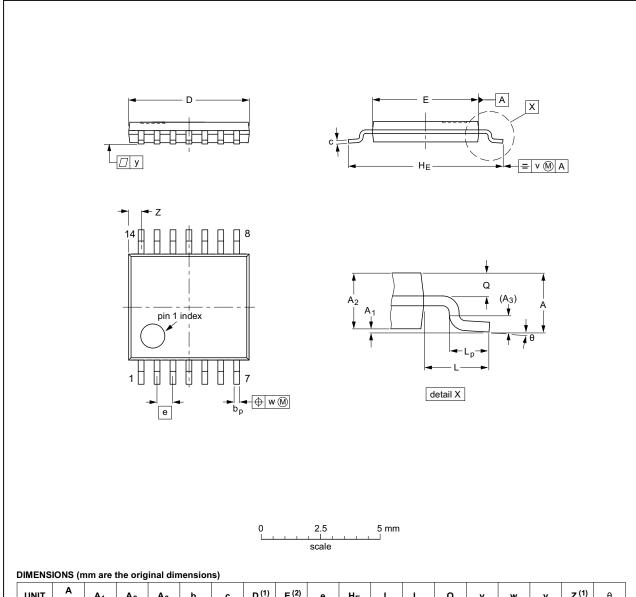
Fig 19. Package outline SOT519-1 (SSOP16)

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TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

SOT402-1



ı	UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽²⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
	mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.72 0.38	8° 0°

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

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		99-12-27 03-02-18	
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Fig 20. Package outline SOT402-1 (TSSOP14)

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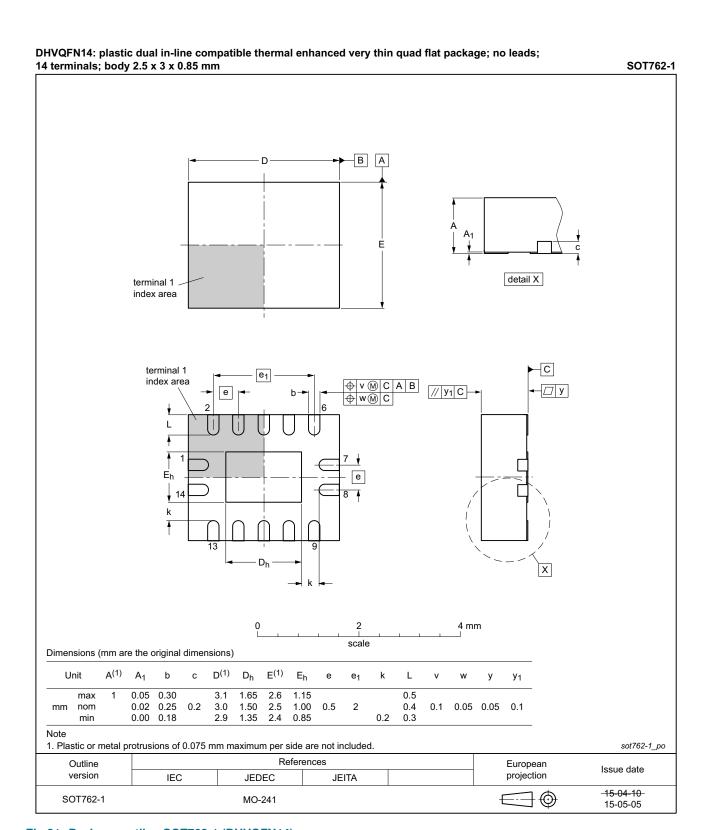


Fig 21. Package outline SOT762-1 (DHVQFN14)

74CBTLV3125

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13. Abbreviations

Table 12. Abbreviations

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model

14. Revision history

Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74CBTLV3125 v.4	20161109	Product data sheet	-	74CBTLV3125 v.3
Modifications:	• <u>Section 11.1</u> a	and Section 11.2 added.		
74CBTLV3125 v.3	20111215	Product data sheet	-	74CBTLV3125 v.2
Modifications:	Legal pages u	pdated.		
74CBTLV3125 v.2	20110104	Product data sheet	-	74CBTLV3125 v.1
74CBTLV3125 v.1	20100108	Product data sheet	-	-

15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition					
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.					
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.					
Product [short] data sheet	Production	This document contains the product specification.					

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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